

# Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

- Extremely Fast Switching Speed
- Low Forward Voltage — 0.35 Volts (Typ) @  $I_F = 10 \text{ mAdc}$

## LBAT54AWT1

30 VOLTS DUAL SERIES  
SCHOTTKY AND BARRIER  
DIODES

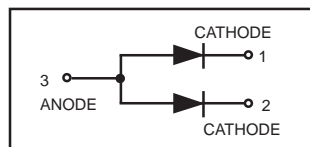


SOT-323 (SC-70)

### ORDERING INFORMATION

Device	Package	Shipping
LBAT54AWT1	SOT-323	3000/Tape & Reel

**Preferred:** devices are recommended choices for future use and best overall value.



### DEVICE MARKING

LBAT54AWT1 = B7

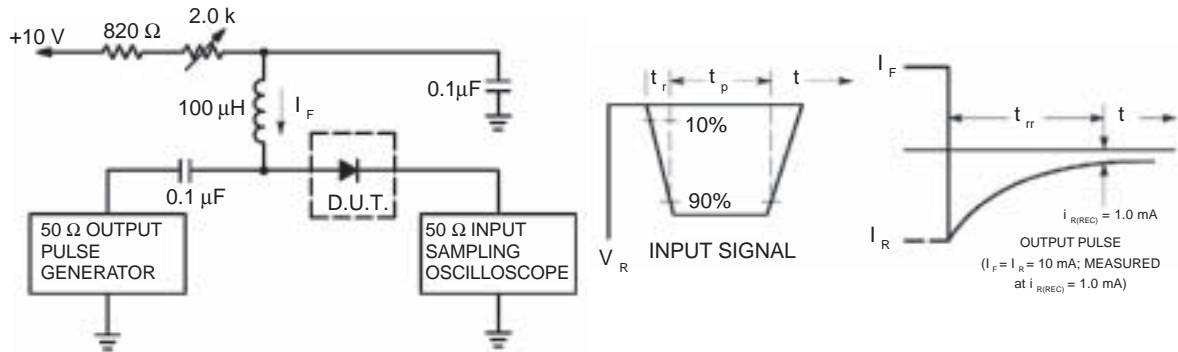
### MAXIMUM RATINGS (T<sub>J</sub> = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	30	Volts
Forward Power Dissipation @ T <sub>A</sub> = 25°C	P <sub>F</sub>	200	mW
Derate above 25°C		1.6	mW/°C
Forward Current(DC)	I <sub>F</sub>	200Max	mA
Junction Temperature	T <sub>J</sub>	125Max	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

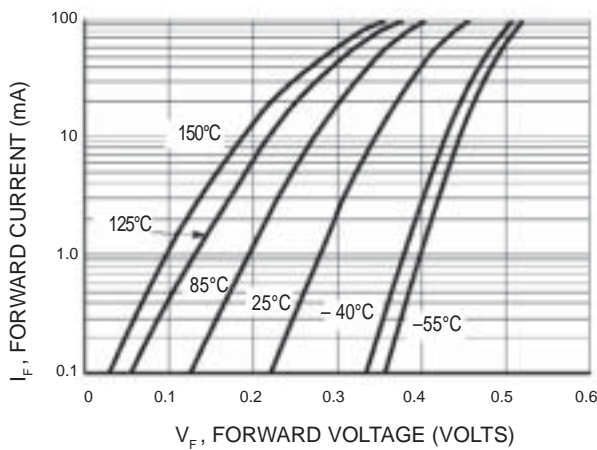
Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μA)	V <sub>(BR)R</sub>	30	—	—	Volts
Total Capacitance (V <sub>R</sub> = 1.0 V, f = 1.0 MHz)	C <sub>T</sub>	—	7.6	10	pF
Reverse Leakage (V <sub>R</sub> = 25 V)	I <sub>R</sub>	—	0.5	2.0	μAdc
Forward Voltage (I <sub>F</sub> = 0.1 mAdc)	V <sub>F</sub>	—	0.22	0.24	Vdc
Forward Voltage (I <sub>F</sub> = 30 mAdc)	V <sub>F</sub>	—	0.41	0.5	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	—	0.52	1.0	Vdc
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mAdc, I <sub>R(REC)</sub> = 1.0 mAdc, Figure 1)	t <sub>rr</sub>	—	—	5.0	ns
Forward Voltage (I <sub>F</sub> = 1.0 mAdc)	V <sub>F</sub>	—	0.29	0.32	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	—	0.35	0.40	Vdc
Forward Current (DC)	I <sub>F</sub>	—	—	200	mAdc
Repetitive Peak Forward Current	I <sub>FRM</sub>	—	—	300	mAdc
Non-Repetitive Peak Forward Current (t < 1.0 s)	I <sub>FSM</sub>	—	—	600	mAdc

**LBAT54AWT1**

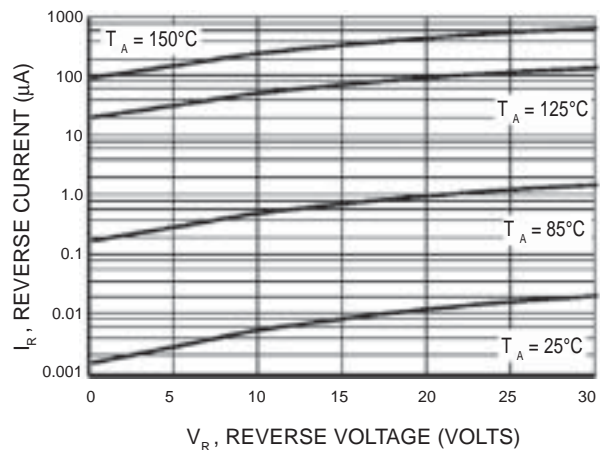


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10mA.  
 3.  $t_p \gg t_{rr}$

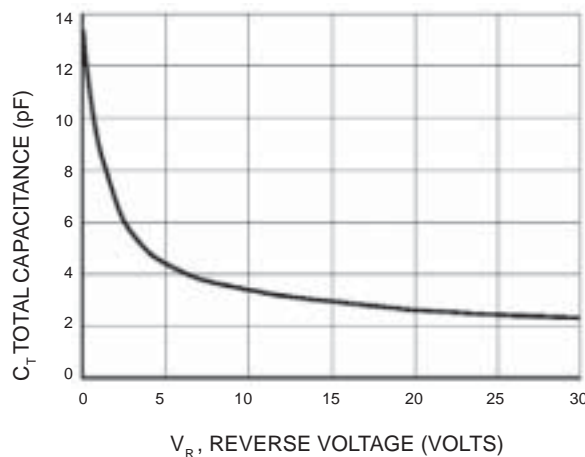
**Figure 1. Recovery Time Equivalent Test Circuit**



**Figure 2. Forward Voltage**



**Figure 3. Leakage Current**



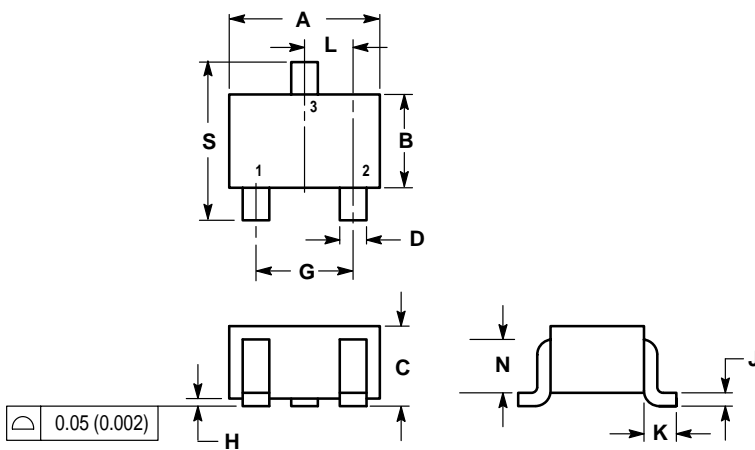
**Figure 4. Total Capacitance**

**LBAT54AWT1**

**SC-70 / SOT-323**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

